HiPerFRED

### DSEC16-06AC

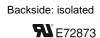
$V_{\text{RRM}}$	=	600 V		
I <sub>FAV</sub>	=2x	10 A		
t <sub>rr</sub>	=	30 ns		

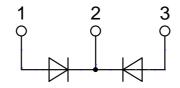
High Performance Fast Recovery Diode Low Loss and Soft Recovery **Common Cathode** 

Part number

DSEC16-06AC







#### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
- Power dissipation within the diode - Turn-on loss in the commutating switch

#### **Applications:**

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)
- Package: ISOPLUS220
- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting

20120705b

- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

#### Terms Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office. Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

IXYS reserves the right to change limits, conditions and dimensions.

Data according to IEC 60747and per semiconductor unless otherwise specified

# LIXYS

# DSEC16-06AC

Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse block	ing voltage	$T_{VJ} = 25^{\circ}C$			600	V
V <sub>RRM</sub>	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			600	V
I <sub>R</sub>	reverse current, drain current	$V_{R} = 600 V$	$T_{VJ} = 25^{\circ}C$			60	μA
		$V_{R} = 600 V$	$T_{v_J} = 150^{\circ}C$			0.25	mA
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 10 A	$T_{vJ} = 25^{\circ}C$			2.10	V
		I <sub>F</sub> = 20 A				2.32	V
		$I_{\rm F} = 10  {\rm A}$	T <sub>vj</sub> = 150°C			1.42	V
		$I_{F} = 20 \text{ A}$				1.68	V
IFAV	average forward current	T <sub>c</sub> =135°C	T <sub>vJ</sub> = 175°C			10	А
		rectangular d = 0.5					
V <sub>F0</sub>	threshold voltage	and a dar the second	T <sub>vJ</sub> = 175°C			1.03	V
r <sub>F</sub>	slope resistance } for power in	oss calculation only				25.1	mΩ
R <sub>thJC</sub>	thermal resistance junction to cas	e				2.5	K/W
R thCH	thermal resistance case to heatsin	nk			0.50		K/W
P <sub>tot</sub>	total power dissipation		$T_c = 25^{\circ}C$			60	W
I <sub>FSM</sub>	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_R = 0 V$	$T_{vJ} = 45^{\circ}C$			50	Α
C	junction capacitance	$V_{R}$ = 400 V f = 1 MHz	$T_{VJ} = 25^{\circ}C$		6		pF
I <sub>RM</sub>	max. reverse recovery current		$T_{VJ} = 25 ^{\circ}C$		4		А
		$I_{\rm F} = 10  \text{A};  V_{\rm R} = 300  \text{V}$	T <sub>vJ</sub> = 100 °C		6		А
t <sub>rr</sub>	reverse recovery time	$\begin{cases} I_{F} = 10 \text{ A}; V_{R} = 300 \text{ V} \\ -di_{F} / dt = 200 \text{ A} / \mu \text{s} \end{cases}$	$T_{VJ} = 25 ^{\circ}C$		30		ns
		)	$T_{vJ} = 100 ^{\circ}C$		90		ns

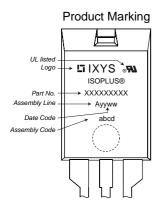
IXYS reserves the right to change limits, conditions and dimensions.

20120705b

# **TIXYS**

# DSEC16-06AC

Package ISOPLUS220				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per terminal 1)				35	А
T <sub>vj</sub>	virtual junction temperature			-55		175	°C
T <sub>op</sub>	operation temperature			-55		150	°C
T <sub>stg</sub>	storage temperature			-55		150	°C
Weight					2		g
F <sub>c</sub>	mounting force with clip			20		60	Ν
d <sub>Spp/App</sub>	creepage distance on surface   s	triking distance through air	terminal to terminal	1.0			mm
d <sub>Spb/Apb</sub>	creepage distance on surface (s	unking distance unough an	terminal to backside	3.0			mm
	isolation voltage	t = 1 second		3600			V
		t = 1 minute	50/60 Hz, RMS; lıso∟ ≤ 1 mA	3000			V



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSEC16-06AC	DSEC16-06AC	Tube	50	505131

Similar Part	Package	Voltage class
DSEC16-06A	TO-220AB (3)	600

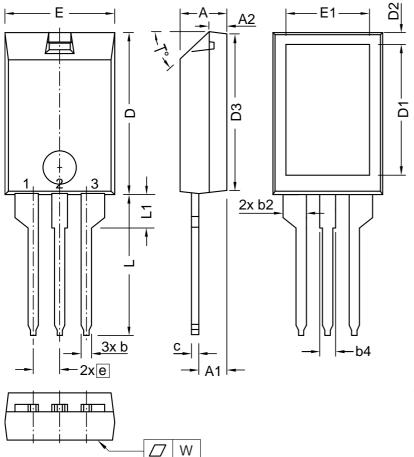
Equivalent Circuits for Simulation		* on die level	T <sub>vj</sub> = 175 °C	
	R₀	Fast Diode		
V <sub>0 max</sub>	threshold voltage	1.03		V
$R_{0 max}$	slope resistance *	22		mΩ

IXYS reserves the right to change limits, conditions and dimensions.

# LIXYS

## DSEC16-06AC

### **Outlines ISOPLUS220**



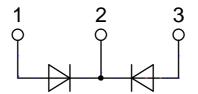
Dim.	Millim	neters	ters Inche	
Dim.	min	max	min	max
Α	4.00	5.00	0.157	0.197
A1	2.50	3.00	0.098	0.118
A2	1.60	1.80	0.063	0.071
b	0.90	1.30	0.035	0.051
b2	2.35	2.55	0.093	0.100
b4	1.25	1.65	0.049	0.065
С	0.70	1.00	0.028	0.039
D	15.00	16.00	0.591	0.630
D1	12.00	13.00	0.472	0.512
D2	1.10	1.50	0.043	0.059
D3	14.90	15.50	0.587	0.610
Е	10.00	11.00	0.394	0.433
E1	7.50	8.50	0.295	0.335
е	2.54	BSC	0.100 BSC	
L	13.00	14.50	0.512	0.571
L1	3.00	3.50	0.118	0.138
T°	42.5	47.5		
W	-	0.1	-	0.004

Die konvexe Form des Substrates ist typ. < 0.04 mm über der Kunststoffoberfläche der Bauteilunterseite The convex bow of substrate is typ. < 0.04 mm over plastic

surface level of device bottom side

Die Gehäuseabmessungen entsprechen dem Typ TO-273 gemäß JEDEC außer D und D1.

This drawing will meet all dimensions requiarement of JEDEC outline TO-273 except D and D1.



IXYS reserves the right to change limits, conditions and dimensions.

20120705b

## DSEC16-06AC

#### **Fast Diode**

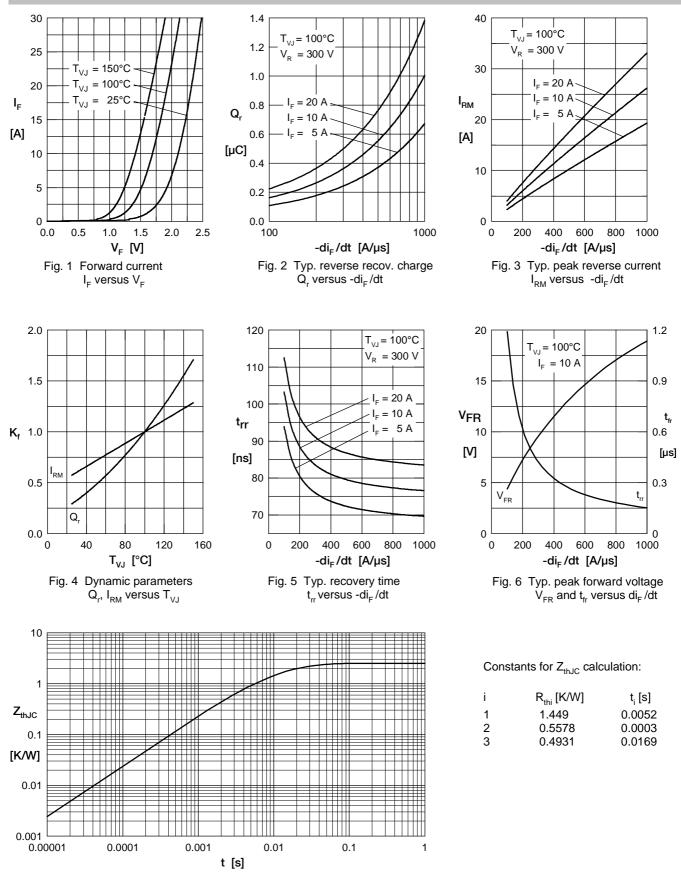


Fig. 7 Transient thermal impedance junction to case

IXYS reserves the right to change limits, conditions and dimensions.

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Rectifiers category:

Click to view products by IXYS manufacturer:

Other Similar products are found below :

 70HFR40
 RL252-TP
 150KR30A
 1N5397
 NTE5841
 NTE6038
 SCF5000
 1N4002G
 1N4005-TR
 JANS1N6640US
 481235F

 RRE02VS6SGTR
 067907F
 MS306
 70HF40
 T85HFL60S02
 US2JFL-TP
 A1N5404G-G
 ACGRA4007-HF
 ACGRB207-HF

 CLH03(TE16L,Q)
 ACGRC307-HF
 ACEFC304-HF
 NTE6356
 NTE6359
 NTE6002
 NTE6023
 NTE6039
 NTE6077
 85HFR60
 40HFR60

 VS-88-7272PBF
 70HF120
 85HFR80
 D126A45C
 SCF7500
 D251N08B
 SCHJ22.5K
 SM100
 SCPA2
 SCH10000
 SDHD5K
 VS 

 12FL100S10
 ACGRA4001-HF
 D1821SH45T
 PR
 D1251S45T
 NTE5990
 NTE6162
 NTE5850